

RN2606(TE85L,F)

RN2606(TE85L,F) Information

	ener.com	RN2606(TE85L,F) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased TRANS 2PNP PREBIAS 0.3W SM6 SC-74, SOT-457 For the pricing/inventory/lead time, please contact us	
For Refere	ence Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RN2606(TE85L,F) Specifications

Manufacturer Part Number	RN2606(TE85L,F)		
Manufacturer	Toshiba Semiconductor and Storage		
Category	Discrete Semiconductor Products		
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased		
Package	SC-74, SOT-457		
Series	-		
Transistor Type	2 PNP - Pre-Biased (Dual)		
Current - Collector (Ic) (Max)	100mA		
Voltage - Collector Emitter Breakdown (Max)	50V		
Resistor - Base (R1) (Ohms)	4.7k		
Resistor - Emitter Base (R2) (Ohms)	47k		
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V		
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA		
Current - Collector Cutoff (Max)	100nA (ICBO)		
Frequency - Transition	200MHz		
Power - Max	300mW		
Mounting Type	Surface Mount		
Package / Case	SC-74, SOT-457		
Supplier Device Package	SM6		
	Report errors?		

RN2606(TE85L,F) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RN2606(TE85L,F) Payment Methods



RN2606(TE85L,F) Shipping Methods



If you have any question about RN2606(TE85L,F), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com